



10/Suppl. and
P. Walker
PATENT 10-150

Customer No. 22,852
Attorney Docket No. 04329.2553

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:)
)
Masaki HATANO, et al.) Group Art Unit: 2822
)
Serial No.: 09/816,177) Examiner: Mitchell, James M.
)
Filed: March 26, 2001)
)
For: SEMICONDUCTOR DEVICE)

Assistant Commissioner for Patents
Washington, DC 20231

Sir:

SUPPLEMENTAL AMENDMENT

Further to the Amendment of April 22, 2002, please amend the application as follows:

IN THE CLAIMS:

Please amend claims 14, 15, 21, and 22 as follows:

14. (Amended) The semiconductor device according to claim 13, wherein a thickness of the TaN film is 20 nm or more.

15. (Amended) The semiconductor device according to claim 13, wherein a thickness of the TaN film is 40 nm or more.

21. (Amended) The semiconductor device according to claim 20, wherein a thickness of the TaN film is 20 nm or more.

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